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5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

SLLS680-DECEMBER 2005

FEATURES

- ESD Protection for RS-232 Bus Pins
 ±15-kV Human-Body Model (HBM)
- Meets or Exceeds the Requirements of TIA/EIA-232-F and ITU v.28 Standards
- Operates at 5-V V_{CC} Supply
- Four Drivers and Five Receivers
- Operates up to 120 kbit/s
- Low Supply Current in Shutdown Mode . . . 15 μA Typ
- External Capacitors . . . 4 × 0.1 F
- Designed to Be Interchangeable With Maxim MAX213
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II

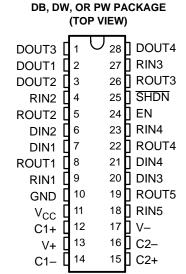
APPLICATIONS

- Battery-Powered Systems
- PDAs
- Notebooks
- Laptops
- Palmtop PCs
- Hand-Held Equipment

DESCRIPTION/ ORDER INFORMATION

The MAX213 device consists of four line drivers, five line receivers, and a dual charge-pump circuit with ± 15 -kV ESD protection pin to pin (serial-port connection pins, including GND). The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 5-V supply. The devices operate at data signaling rates up to 120 kbit/s and a maximum of 30-V/ μ s driver output slew rate.

The MAX213 has an active-low shutdown (\overline{SHDN}) and an active-high enable control (EN). In shutdown mode, the charge pumps are turned off, V+ is pulled down to V_{CC}, V- is pulled to GND, and the transmitter outputs are disabled. This reduces supply current typically to 1 μ A. Two receivers of the MAX213 are active during shutdown.



MAX213 5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION





ORDERING INFORMATION

T _A	PACKAGE ⁽¹⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
	SOIC - DW	Tube of 20	MAX213CDW	
	SOIC - DW	Reel of 1000	MAX213CDWR	
0°C to 70°C	SSOP – DB	Tube of 50	MAX213CDB	
	220b – DB	Reel of 2000	MAX213CDBR	
	TSSOP - PW	Tape and reel	MAX213CPWR	
	SOIC - DW	Tube of 20	MAX213IDW	
	201C – DW	Reel of 1000	MAX213IDWR	
–40°C to 85°C	CCOD DD	Tube of 50	MAX213IDB	
	SSOP – DB	Reel of 2000	MAX213IDBR	
	TSSOP - PW	Tape and reel	MAX213IPWR	

⁽¹⁾ Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

FUNCTION TABLE

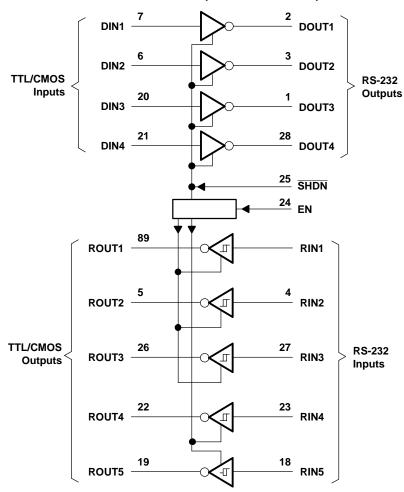
INP	UTS	DRIVER	REC	DEVICE STATUS	
SHDN	EN	D1-D4	R1-R3	R4-R5	DEVICE STATUS
L	L	Z	Z	Z	Shutdown
L	Н	Z	Z	Active ⁽¹⁾	Shutdown
Н	L	All active	Z	Z	Normal operation
Н	Н	All active	Active	Active	Normal operation

(1) See the V_{IT+} and V_{IT-} change in the *Electrical Characteristics* table.



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LOGIC DIAGRAM (POSITIVE LOGIC)



MAX213 5-V MULTICHANNEL RS-232 LINE DRIVER/RECEIVER WITH ±15-kV ESD PROTECTION

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Absolute Maximum Ratings⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V _{CC}	Supply voltage range		-0.3	6	V
V+	Positive charge-pump voltage range ⁽²⁾		V _{CC} - 0.3	14	V
V-	Negative charge-pump voltage range ⁽²⁾		0.3	-14	V
V	Innut voltage renge	Drivers	-0.3	V+ + 0.3	V
V _I	Input voltage range	Receivers		±30	V
\/	Output voltage range	Drivers	V0.3	V+ + 0.3	V
Vo	Output voltage range	Receivers	-0.3	V _{CC} + 0.3	V
DOUT	Short-circuit duration		C	ontinuous	
		DB package		62	
θ_{JA}	Package thermal impedance (3)(4)	DW package		46	
		PW package			
T _J	Operating virtual junction temperature	·		150	C°
T _{stg}	Storage temperature range		-65	150	C°

⁽¹⁾ Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

All voltages are with respect to network GND.

Recommended Operating Conditions⁽¹⁾

See Figure 4

		MIN	NOM	MAX	UNIT	
	Supply voltage	4.5	5	5.5	V	
V	Driver high-level input voltage DIN				V	
V_{IH}	Control high-level input voltage EN, SHDN	2.4			V	
V_{IL}	Driver and control low-level input voltage DIN, EN, SHD	N		0.8	V	
Vı	Driver and control input voltage DIN, EN, SHD	N 0		5.5	V	
٧I	Receiver input voltage RIN			30	V	
т	Operating free air temperature	0		70	°C	
IA	Operating free-air temperature MAX213I			85		

⁽¹⁾ Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V.

Electrical Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	Т	MIN	TYP ⁽²⁾	MAX	UNIT	
I _{CC}	Supply current	No load,	See Figure 6		14	20	mA
I _{SHDN}	Shutdown supply current	T _A = 25°C,	See Figure 1		15	50	μΑ

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V.

Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability. The package thermal impedance is calculated in accordance with JESD 51-7.

All typical values are at $V_{CC} = 5 \text{ V}$, and $T_A = 25^{\circ}\text{C}$.



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DRIVER SECTION

Electrical Characteristics(1)

over operating free-air temperature range (unless otherwise noted) (see Figure 4)

	PARAMETER	TEST CONDI	TIONS	MIN	TYP ⁽²⁾	MAX	UNIT
V_{OH}	High-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GNI	DOUT at $R_L = 3 \text{ k}\Omega$ to GND		9		V
V_{OL}	Low-level output voltage	DOUT at $R_L = 3 \text{ k}\Omega$ to GNI	DOUT at $R_L = 3 \text{ k}\Omega$ to GND				V
I _{IH}	Control high-level input current	EN, SHDN = 5 V			3	10	μΑ
	Driver low-level input current	DIN = 0 V			-15	-200	
IIL	Control low-level input current	EN, SHDN = 0 V			-3	-10	μΑ
I _{OS} (3)	Short-circuit output current	$V_{CC} = 5.5 \text{ V},$	V _O = 0 V		±10	±60	mA
r _o	Output resistance	V_{CC} , V+, and V- = 0 V,	V _O = ±2 V	300			Ω

Switching Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CON	TEST CONDITIONS			MAX	UNIT
Maximum data rate		C _L = 50 pF to 1000 pF, One DOUT switching,					kbit/s
t _{PLH(D)}	Propagation delay time, low- to high-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$, See Figure 3	2		μs	
t _{PHL(D)}	Propagation delay time, high- to low-level output	C _L = 2500 pF, All drivers loaded,	$R_L = 3 k\Omega$, See Figure 3		2		μs
t _{sk(p)}	Pulse skew ⁽³⁾	C _L = 150 pF to 2500 pF, See Figure 3	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	300			ns
SR(tr)	Slew rate, transition region (see Figure 2)	C _L = 50 pF to 1000 pF, V _{CC} = 5 V	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	3	6	30	V/μs

ESD Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
DOUT	Human-Body Model	±15	kV

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V All typical values are at V_{CC} = 5 V, and T_A = 25°C. Short-circuit durations should be controlled to prevent exceeding the device absolute power dissipation ratings, and not more than one output should be shorted at a time.

Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C. Pulse skew is defined as (t_{PLH} - t_{PHL}) of each channel of the same device.

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RECEIVER SECTION

Electrical Characteristics(1)

over operating free-air temperature range (unless otherwise noted) (see Figure 6)

	PARAMETER	TEST	MIN	TYP ⁽²⁾	MAX	UNIT	
V _{OH}	High-level output voltage	$I_{OH} = -1 \text{ mA}$			V _{CC} - 0.4		V
V_{OL}	Low-level output voltage	I _{OH} = 1.6 mA				0.4	٧
V	Positive-going input threshold voltage	V - 5 V T - 25°C	Active mode		1.7	2.4	٧
V_{IT+}		$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$	Shutdown mode (R4-R5)		1.5	2.4	V
\/	Negative-going		Active mode	0.8	1.2		V
V_{IT-}	input threshold voltage	V _{CC} = 5 V, T _A = 25°C Shutdown mode (R4–R5)		0.6	1.5		v
Vhys ⁽³⁾	Input hysteresis (V _{IT+} , V _{IT-})	V _{CC} = 5 V	V _{CC} = 5 V			1	V
r _l	Input resistance	$V_{CC} = 5 \text{ V}, T_A = 25^{\circ}\text{C}$		3	5	7	kΩ
	Output leakage current	EN = 0 V, 0 ≤ ROUT ≤ V	EN = 0 V, 0 ≤ ROUT ≤ V _{CC} , R1–R3			±10	μΑ

⁽¹⁾ Test conditions are C1–C4 = 0.1 μ F at V_{CC} = 5 V \pm 0.5 V. (2) All typical values are at V_{CC} = 5 V, and T_A = 25°C. (3) No hysteresis in shudown mode

Switching Characteristics⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

	PARAMETER		MIN TYP ⁽²⁾	MAX	UNIT		
	Propagation delay time,	C 450 pF	Coo Figure 4	SHDN = V _{CC}	0.5	10	
τ _{PLH(R)}	low- to high-level output	$C_L = 150 \text{ pF},$	See Figure 4	SHDN = 0 V, R4-R5	4	40	μs
t _{PHL(R)}	Propagation delay time, high- to low-level output	C _L = 150 pF,	See Figure 4		0.5	10	μs
t _{en}	Output enable time	$C_L = 150 \text{ pF},$	See Figure 5		600		ns
t _{dis}	Output disable time	$C_L = 150 \text{ pF},$	See Figure 5		200		ns

Test conditions are C1–C4 = 0.1 μF at V_{CC} = 5 V \pm 0.5 V. All typical values are at V_{CC} = 5 V, and T_A = 25°C.

ESD Protection

over operating free-air temperature range (unless otherwise noted)

PIN	TEST CONDITIONS	TYP	UNIT
RIN	Human-Body Model	±15	kV





PARAMETER MEASUREMENT INFORMATION

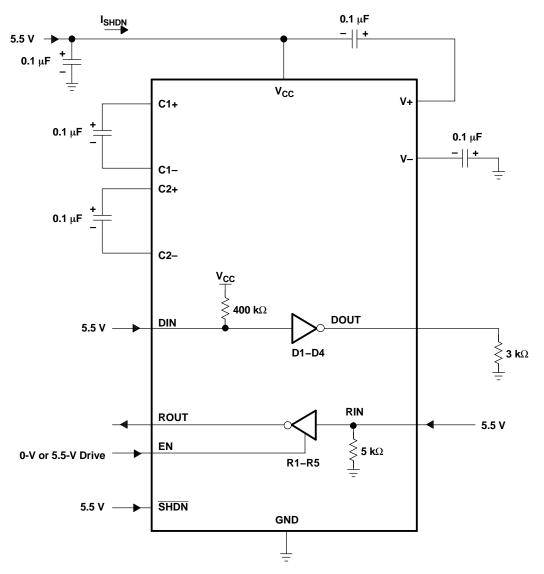
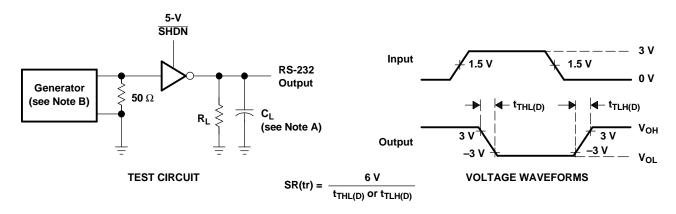


Figure 1. Shutdown Current Test Circuit



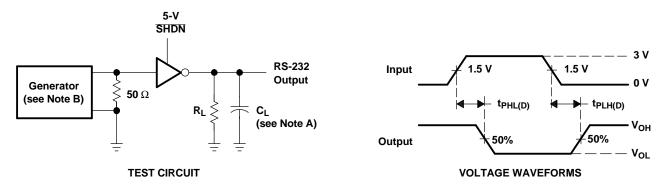
PARAMETER MEASUREMENT INFORMATION (continued)



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: $Z_O = 50 \ \Omega$, 50% duty cycle, $t_r \le 10 \ ns$.

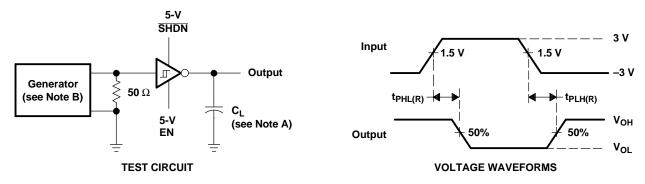
Figure 2. Driver Slew Rate



NOTES: A. C_L includes probe and jig capacitance.

B. The pulse generator has the following characteristics: Z_O = 50 Ω , 50% duty cycle, $t_r \le$ 10 ns, $t_f \le$ 10 ns.

Figure 3. Driver Pulse Skew and Propagation Delay Times



NOTES: A. C_L includes probe and jig capacitance.

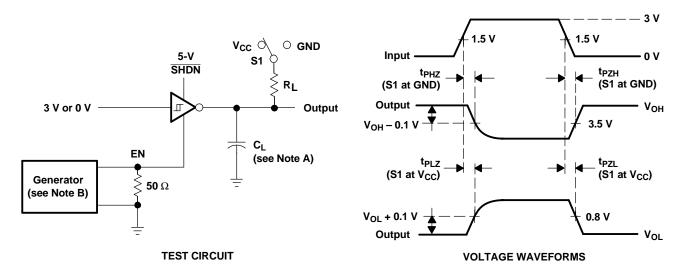
B. The pulse generator has the following characteristics: $Z_0 = 50 \ \Omega$, 50% duty cycle, $t_f \le 10 \ ns$.

Figure 4. Receiver Propagation Delay Times



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PARAMETER MEASUREMENT INFORMATION (continued)



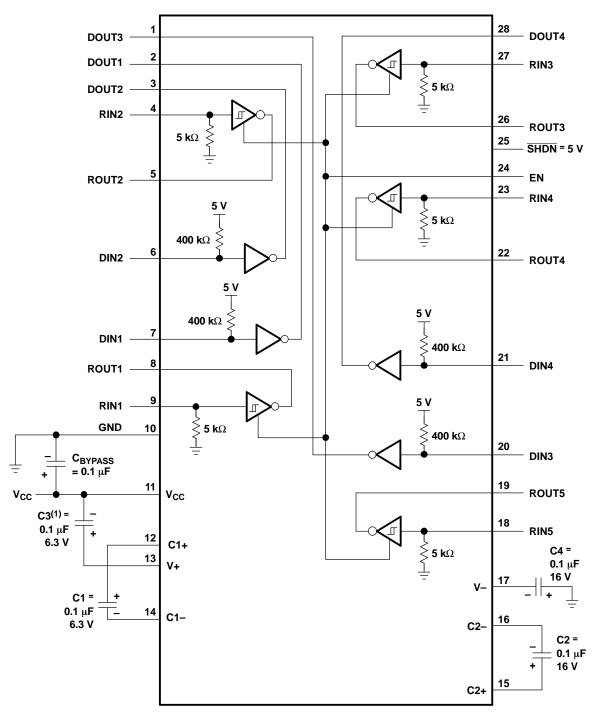
NOTES: A. C_L includes probe and jig capacitance.

- B. The pulse generator has the following characteristics: Z_0 = 50 Ω , 50% duty cycle, $t_r \le 10$ ns. $t_f \le 10$ ns.
- C. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
- D. t_{PZL} and t_{PZH} are the same as t_{en} .

Figure 5. Receiver Enable and Disable Times



APPLICATION INFORMATION



(1) C3 can be connected to $V_{\mbox{\footnotesize CC}}$ or GND.

NOTES: A. Resistor values shown are nominal.

B. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Figure 6. Typical Operating Circuit and Capacitor Values







PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
MAX213CDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDBG4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDBRG4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDWG4	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213CDWRG4	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDB	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDBG4	ACTIVE	SSOP	DB	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDBR	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDBRG4	ACTIVE	SSOP	DB	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDW	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDWG4	ACTIVE	SOIC	DW	28	20	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDWR	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
MAX213IDWRG4	ACTIVE	SOIC	DW	28	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽²⁾ Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



PACKAGE OPTION ADDENDUM

28-May-2007

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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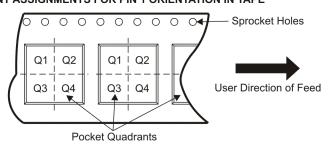
TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
MAX213CDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX213CDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1
MAX213IDBR	SSOP	DB	28	2000	330.0	16.4	8.2	10.5	2.5	12.0	16.0	Q1
MAX213IDWR	SOIC	DW	28	1000	330.0	32.4	11.35	18.67	3.1	16.0	32.0	Q1





*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
MAX213CDBR	SSOP	DB	28	2000	346.0	346.0	33.0
MAX213CDWR	SOIC	DW	28	1000	346.0	346.0	49.0
MAX213IDBR	SSOP	DB	28	2000	346.0	346.0	33.0
MAX213IDWR	SOIC	DW	28	1000	346.0	346.0	49.0

DW (R-PDSO-G28)

PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AE.



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